

HSK83

Silicon Epitaxial Planar Diode for High Voltage Switching

HITACHI

ADE-208-169C(Z)

Rev 3

Dec. 1998

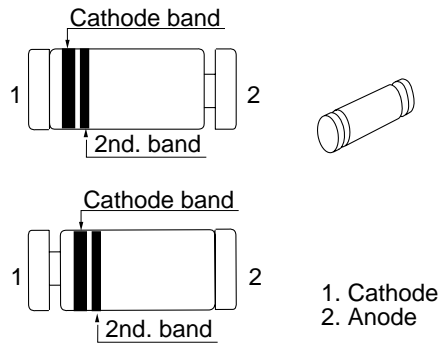
Features

- High reverse voltage. ($V_R=250V$)
- LLD package is suitable for high density surface mounting and high speed assembly

Ordering Information

Type No.	Cathode band	2nd band	Package Code
HSK83	White	Verdure	LLD

Outline



Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Value	Unit
Peak reverse voltage	V_{RM}	300	V
Reverse voltage	V_R	250	V
Peak forward current	I_{FM}	625	mA
Non-Repetitive peak forward surge current	I_{FSM}^{*1}	1	A
Average rectified current	I_O	150	mA
Junction temperature	T_j	175	°C
Storage temperature	T_{stg}	-65 to +175	°C

Note 1. Value at duration of 1s.

Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Forward voltage	V_F	—	—	1.0	V	$I_F = 100\text{ mA}$
Reverse current	I_{R1}	—	—	0.1	μA	$V_R = 250\text{V}$
	I_{R2}	—	—	100		$V_R = 300\text{V}$
Capacitance	C	—	1.5	—	pF	$V_R = 0\text{V}$, $f = 1\text{ MHz}$
Reverse recovery time	t_{rr}	—	—	100	ns	$I_F = I_R = 30\text{ mA}$, $I_{rr} = 3\text{mA}$, $R_L = 100\Omega$

Main Characteristic

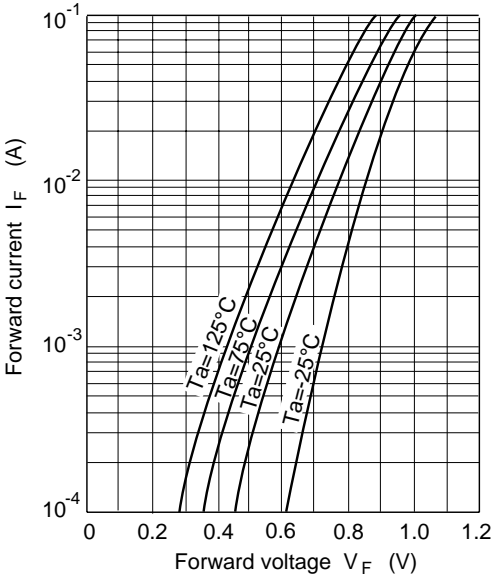


Fig.1 Forward current Vs. Forward voltage

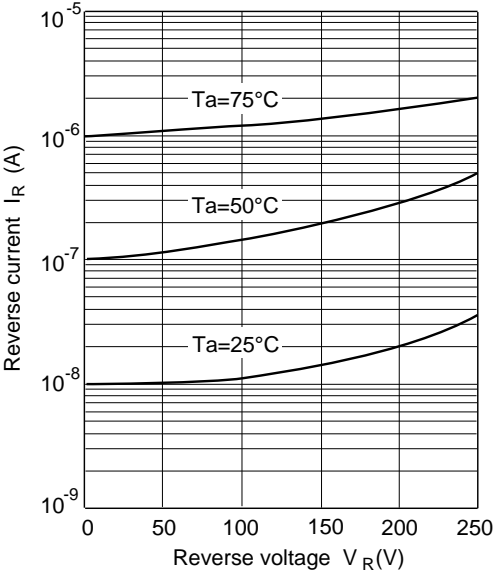


Fig.2 Reverse current Vs. Reverse voltage

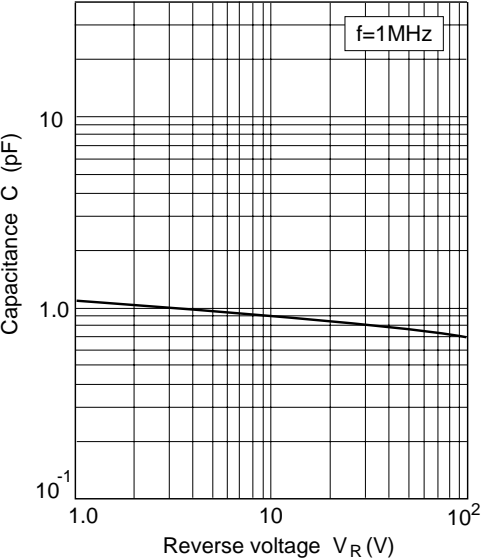
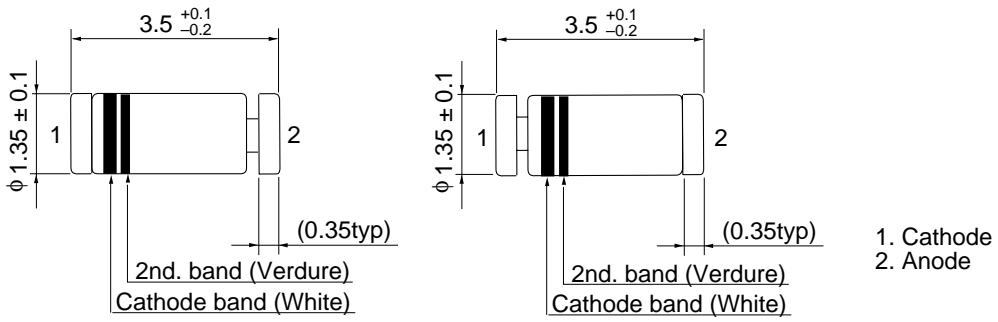


Fig.3 Capacitance Vs. Reverse voltage

Package Dimensions

Unit : mm



() : Reference only

Hitachi Code	LLD
JEDECCode	
EIAJCode	
Weight(g)	0.027

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Hitachi, Ltd.

Semiconductor & IC Div.
 Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
 Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL NorthAmerica : <http://semiconductor.hitachi.com/>
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For further information write to:

<p>Hitachi Semiconductor (America) Inc. 2000 Sierra Point Parkway Brisbane, CA 94005-1897 Tel: <1> (800) 285-1601 Fax: <1> (303) 297-0447</p>	<p>Hitachi Europe GmbH Electronic components Group Dornacher Straße 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00</p> <p>Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322</p>	<p>Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533</p> <p>Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building, No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180</p>	<p>Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218 Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX</p>
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